Gallium Arsenide CATV Amplifier Module

Features

- Specified for 79-, 112- and 132-Channel Loading
- **Excellent Distortion Performance**
- Built-in Input Diode Protection
- GaAs FET Transistor Technology
- Unconditionally Stable Under All Load Conditions

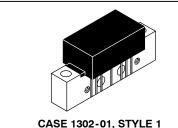
Applications

- CATV Systems Operating in the 40 to 870 MHz Frequency Range
- Input Stage Amplifier in Optical Nodes, Line Extenders and Trunk Distribution Amplifiers for CATV Systems
- Output Stage Amplifier on Applications Requiring Low Power Dissipation and High Output Performance
- Driver Amplifier in Linear General Purpose Applications

- 24 Vdc Supply, 40 to 870 MHz, CATV GaAs Forward Amplifier Module
- Replaced MHW9146. There are no form, fit or function changes with this part replacement.
- **RoHS Compliant**

MHW9146N

870 MHz **14.3 dB GAIN** 132-CHANNEL **GaAs CATV AMPLIFIER MODULE**



CASE 1302-01, STYLE 1

Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
RF Voltage Input (Single Tone)	V _{in}	+65	dBmV
DC Supply Voltage	V _{CC}	+26	Vdc
Operating Case Temperature Range	T _C	-20 to +100	°C
Storage Temperature Range	T _{stg}	-40 to +100	°C

Table 2. ESD Maximum Ratings

Rating	Input Value	Output Value	Unit
Surge Voltage per IEC 1000-4-5	200	200	V
Human Body Model per Mil. Std. 1686	2	2	kV

Table 3. Electrical Characteristics ($V_{CC} = 24 \text{ Vdc}$, $T_{C} = +45^{\circ}\text{C}$, 75 Ω system unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
Frequency Range		BW	40	_	870	MHz
Power Gain	870 MHz	G _p	13.8	14.3	14.8	dB
Slope	40-870 MHz	S	0	0.4	1.0	dB
Gain Flatness (40-870 MHz, Peak-to-Valley)		G _F	_	_	0.5	dB
Return Loss — Input		IRL				dB
(Z _o = 75 Ohms)	40-500 MHz		20	_		
	f > 501 MHz		18		_	
Return Loss — Output		ORL				dB
(Z _o = 75 Ohms)	40-160 MHz		20	_	_	
	f > 160 MHz		18	_	_	

Table 3. Electrical Characteristics (V_{CC} = 24 Vdc, T_{C} = +45°C, 75 Ω system unless otherwise noted) (continued)

Characteristic		Symbol	Min	Тур	Max	Unit
Composite Second Order (V _{out} = +48 dBmV/ch., Worst Case) (V _{out} = +46 dBmV/ch., Worst Case) (V _{out} = +44 dBmV/ch., Worst Case)	79-Channel FLAT 112-Channel FLAT 132-Channel FLAT	CSO ₇₉ CSO ₁₁₂ CSO ₁₃₂	_ _ _	-68 -63 -63	-64 -60 -60	dBc
Cross Modulation Distortion @ Ch 2 (V _{out} = +48 dBmV/ch., FM = 55.25 MHz) (V _{out} = +46 dBmV/ch., FM = 55.25 MHz) (V _{out} = +44 dBmV/ch., FM = 55.25 MHz)	79-Channel FLAT 112-Channel FLAT 132-Channel FLAT	XMD ₇₉ XMD ₁₁₂ XMD ₁₃₂	_ _ _ _	-60 -60 -60	-55 -55 -55	dBc
Composite Triple Beat (V _{out} = +48 dBmV/ch., Worst Case) (V _{out} = +46 dBmV/ch., Worst Case) (V _{out} = +44 dBmV/ch., Worst Case)	79-Channel FLAT 112-Channel FLAT 132-Channel FLAT	CTB ₇₉ CTB ₁₁₂ CTB ₁₃₂	_ _ _	-64 -64 -64	-60 -60 -60	dBc
Noise Figure	50 MHz 550 MHz 750 MHz 870 MHz	NF	_ _ _ _	4.4 3.8 4.0 4.3	5.5 — — 5.5	dB
DC Current (V _{DC} = 24 V, T _C = 45°C)		I _{DC}	230	245	260	mA

Note: This device requires an external 0.01 µF DC blocking capacitor connected to the output pin (Pin 9) as indicated in Figure 1.

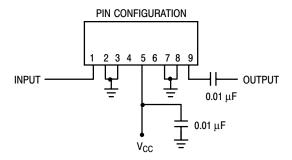
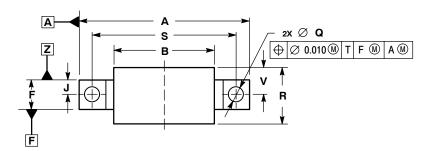
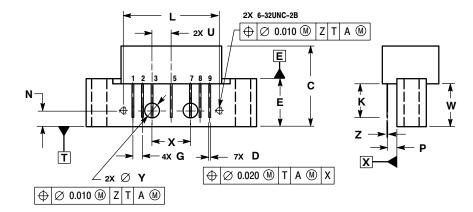


Figure 1. External Connections

PACKAGE DIMENSIONS





- NOTES:
 1. DIMENSIONS ARE IN INCHES.
 2. INTERPRET DIMENSIONS AND INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α		1.775		45.085	
В		1.085		27.559	
С		0.840		21.336	
D	0.015	0.021	0.381	0.533	
E	0.465	0.510	11.811	12.954	
F	0.300	0.325	7.62	8.255	
G	0.100	BSC	2.540 BSC		
J	0.156	BSC	3.962 BSC		
K	0.315	0.355	8.001	9.017	
L	1.000	1.000 BSC		0 BSC	
N	0.165	BSC	4.191 BSC		
P	0.100	BSC	2.540	BSC	
Q	0.148	0.168	3.759	4.267	
R		0.600		15.24	
S	1.500 BSC		38.100 BSC		
U	0.200 BSC		5.080 BSC		
V		0.250		6.350	
W	0.435		11.049		
X	0.400	BSC	10.160 BSC		
Y	0.152	0.163	3.861	4.140	
Z	0.009	0.011	0.229	0.279	

- STYLE 1:
 PIN 1. RF INPUT
 2. GROUND
 3. GROUND
 4. DELETED
 5. VDC
 6. DELETED
 7. GROUND
 8. GROUND
 9. RF OUTPUT

CASE 1302-01 ISSUE E

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